

10-Element Phototransistor Card Reader Array

Optoelectronic Products

FPA720 FPA720A

General Description

The FPA720 and FPA720A are 9-element npn Planar phototransistor arrays with exceptionally stable characteristics and high illumination sensitivity. Each transistor is electrically isolated and mounted on 100 mil centers. The case is a plastic compound with transparent resin encapsulation that exhibits stable characteristics under high humidity conditions.

High Illumination Sensitivity

Especially Designed For Punched Or Marked Card Reading And Optical Encoder Applications

Absolute Maximum Ratings

Maximum Temperatures and Humidity

| | |
|-----------------------------------|-----------------|
| Storage Temperature | -40°C to +100°C |
| Operating Temperature | -40°C to +85°C |
| Pin Temperature (Soldering, 10 s) | 260°C |
| Relative Humidity at 65°C | 85% |

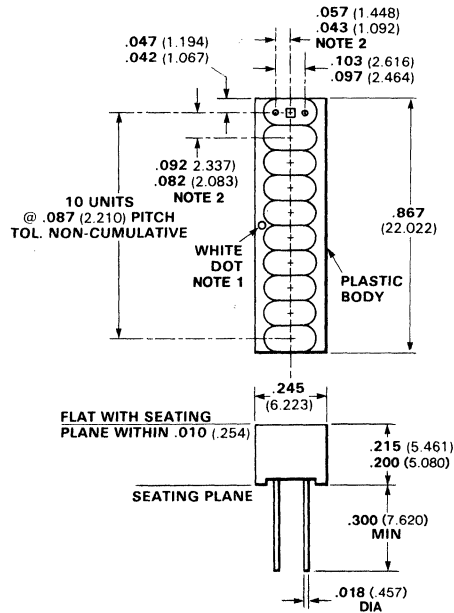
Maximum Power Dissipation per Cell

| | |
|---|------------|
| Total Dissipation at $T_C = 25^\circ\text{C}$ | 200 mW |
| Derate Linearly from 25°C | 3.33 mW/°C |
| Total Dissipation at $T_A = 25^\circ\text{C}$ | 133 mW |
| Derate Linearly from 25°C | 2.22 mW/°C |

Maximum Voltages and Currents (Note 1)

| | |
|---|-------|
| $V_{CE(sus)}$ Collector-to-Emitter Sustaining Voltage | 20 V |
| I_C Collector Current | 25 mA |

Package Outline



Notes

1. Emitter terminal side of phototransistor (sensor array) or anode terminal side of diode (source array) defined by white dot.
2. The center of each element is aligned to $\pm .010$ along the length and $\pm .005$ across the width.
3. All dimensions in inches bold and millimeters (parentheses).
4. Tolerance unless specified = ± 0.15 (0.381).

Typical Electrical Characteristics

FPA720 FPA720A

Electrical Characteristics $T_A = 25^\circ\text{C}$

| Symbol | Characteristic | Min | Typ | Max | Units | Test Conditions |
|-------------------|--|-------------|--------------|------------|---------------|--|
| $V_{CE0(sus)}$ | Collector-to-Emitter Sustaining Voltage (Note 7) | 20 | 35 | | V | $I_C = 1.0\text{ mA}$ pulsed |
| BV_{ECO} | Emitter-to-Collector Breakdown Voltage (Note 7) | | 7.0 | | V | $I_{EC} = 100\ \mu\text{A}$ |
| $V_{CE(sat)}$ | Collector-to-Emitter Saturation Voltage | | 0.16 | 0.33 | V | $I_C = 500\ \mu\text{A}$, $H = 20\text{ mW/cm}^2$ |
| I_{CEO} | Collector Dark Current / Cell (Note 2) | | 4.0 | 100 | nA | $V_{CE} = 5.0\text{ V}$ |
| $I_{CE(t)}$ | Photo Current, Tungsten Source (Note 3) | 200 | 750 | | μA | $V_{CE} = 5.0\text{ V}$, $H = 5\text{ mW/cm}^2$ |
| $I_{CE(t)}$ | Photo Current, Tungsten Source (Note 3) | | 1.75 | | mA | $V_{CE} = 5.0\text{ V}$, $H = 10\text{ mW/cm}^2$ |
| $I_{CE(t)}$ | Photo Current, GaAs Source (Note 4) | | 2.25 | | mA | $V_{CE} = 5.0\text{ V}$, $H = 5\text{ mW/cm}^2$ |
| t_r | Light Current Rise Time (Note 6) | | 4.0 | | μs | GaAs, $I_C = 2.0\text{ mA}$, $R_L = 100\ \Omega$, $V_{CC} = 5.0\text{ V}$ |
| t_f | Light Current Fall Time (Note 6) | | 4.0 | | μs | |
| S_{min}/S_{max} | Matching Factor (Notes 3 and 5) FPA720 FPA720A | 0.5 0.75 | 0.65 0.85 | 1.0 1.0 | | $V_{CE} = 5.0\text{ V}$, $H = 5\text{ mW/cm}^2$ |

Notes

- These are steady-state limits. The factory should be consulted on applications involving pulsed or low duty cycle operation.
- Measured with radiation flux intensity of less than $0.1\ \mu\text{W/cm}^2$ over the spectrum from 0.1 micron to 1.5 microns.
- Measured at noted irradiance as emitted from a tungsten lamp at a color temperature of 2854°K . The effective photosensitive area is (0.8 mm^2) . Illuminance (in lumens/ft²) = irradiance H (in mW/cm^2) $\times 20$ at a color temperature of 2854°K .
- Measured at an irradiance of 5.0 mW/cm^2 as emitted from a gallium arsenide diode.
- Matching factor is the ratio of minimum sensitivity to maximum sensitivity of any two cells.
- Rise time is defined as the time required for I_{CE} to rise from 10% to 90% of the peak value. Fall time is defined as the time required for I_{CE} to decrease from 90% to 10% of peak value.
- Rating refers to a high current point where collector-to-emitter voltage is lowest.

Photo Current Characteristics

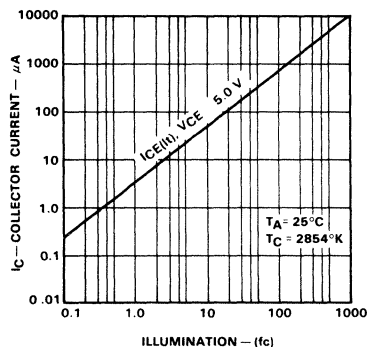
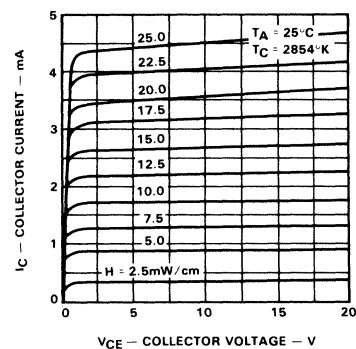


Photo Current vs Collector Voltage

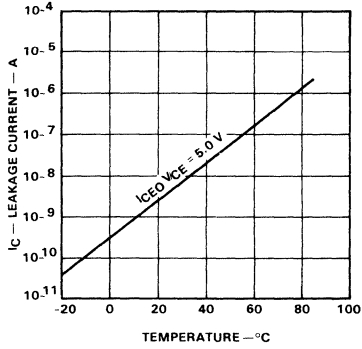


Typical Electrical Characteristic Curves

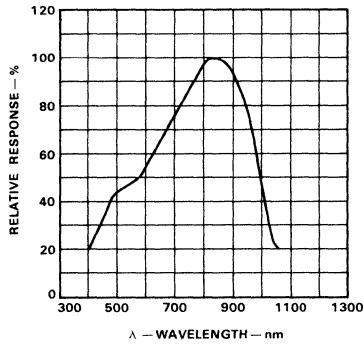
FPA720 FPA720A

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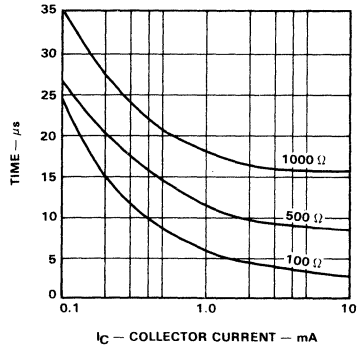
Collector Dark Current vs Temperature



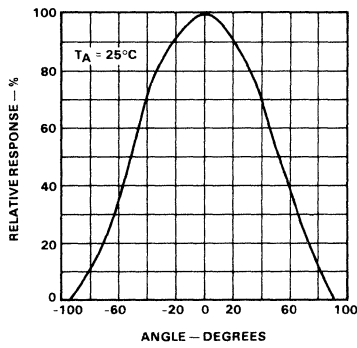
Relative Spectral Response



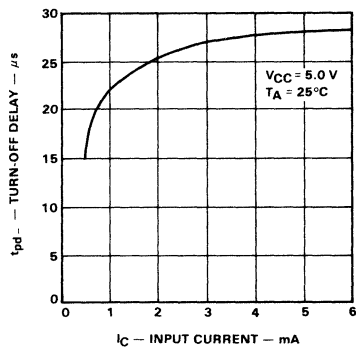
Rise And Fall Time vs Collector Current



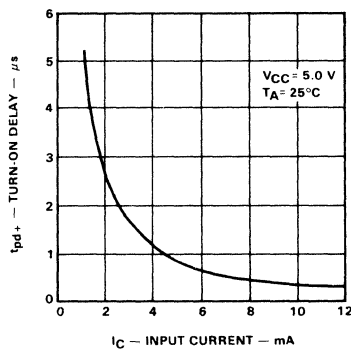
Angular Response



Turn-Off Delay Times



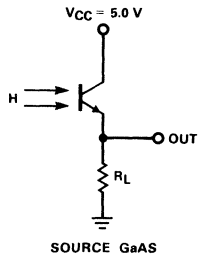
Turn-On Delay Times



Test Circuits

FPA720 FPA720A

Switching Circuit For Rise And Fall Times



Circuit For Turn-On And Turn-Off Delay

